

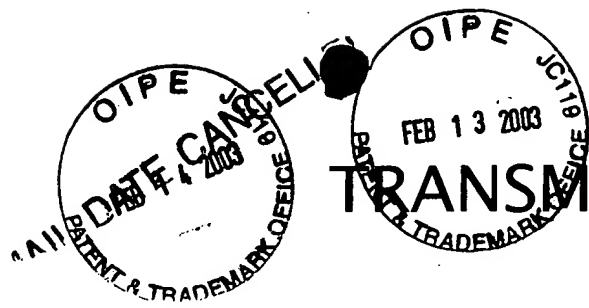
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Electronic Patent Application Submission
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EFS ID: 23230
Application ID: 09955641
Title of Invention: SEMICONDUCTOR MEMORY CELL
AND MEMORY ARRAY USING A
BREAKDOWN PHENOMENA IN AN
ULTRA-THIN DIELECTRIC
First Named Inventor: Jack Peng
Domestic/Foreign Application: Domestic Application
Filing Date: 2001-09-18
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Submission Type: Information Disclosure Statement
Filing Type: null
Confirmation Number: 1777
Attorney Docket Number: 384848001US
Digital Certificate Holder: cn=Robert G. Woolston, ou=Registered Attorneys, ou=Patent and
Trademark Office, ou=Department of Commerce, o=U.S.
Government, c=US
Certificate Message Digest: 20mARD+O1U7qBYm+CagD6A==



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Submission Type: Information
Disclosure Statement

Application Number: 09/955,641
Attorney Docket Number: 384848001US

SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

First Named Inventor: Jack Zezhong Peng

SUBMITTED BY

Name: Chun M. Ng
Registration Number: 36,878
Electronic Signature Mark: /CMN/ Date Signed: 20030213

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Attached Files:

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Electronic Information Disclosure Statement


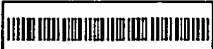
SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

Application: 
09/955641
Confirmation: 1777
Applicant(s): Jack Peng
Docket Number: 384848001.US
Group Art Unit: 2824
Examiner: Hien N. Nguyen
search string: (4677742 or 4599705).pn.

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US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
	P01	4677742	1987-07-07		Johnson	29	591
	P02	4599705	1986-07-08		Holmberg et al.	365	163

Signature

Examiner Name	Date